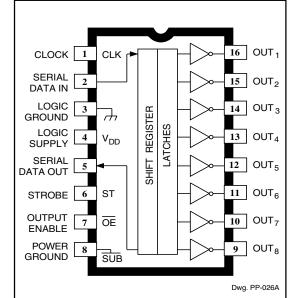
5821 AND 5822

BiMOS II 8-BIT SERIAL-INPUT, LATCHED DRIVERS

A merged combination of bipolar and MOS technology gives these devices an interface flexibility beyond the reach of standard logic buffers and power driver arrays. The UCN5821A, UCN5821LW, UCN5822A, and UCN5822LW each have an eight-bit CMOS shift register and CMOS control circuitry, eight CMOS data latches, and eight bipolar current-sinking Darlington output drivers. The UCN5821A/LW and UCN5822A/LW are identical except for rated output voltage.

BiMOS II devices have much higher data-input rates than the original BiMOS circuits. With a 5 V logic supply, they will typically operate at better than 5 MHz. With a 12 V supply, significantly higher speeds are obtained. The CMOS inputs are compatible with standard CMOS and NMOS logic levels. TTL circuits may require the use of appropriate pull-up resistors. By using the serial data output, the drivers can be cascaded for interface applications requiring additional drive lines.

The UCN5821/22A are furnished in a standard 16-pin plastic DIP; the UCN5821/22LW are in a 16-lead wide-body SOIC for surface-mount applications. The UCN5821A is also available for operation from -40°C to +85°C. To order, change the prefix from 'UCN' to 'UCQ'.



Note the DIP package and the SOIC package are electrically identical and share common terminal number assignments.

ABSOLUTE MAXIMUM RATINGS at 25°C Free-Air Temperature

Output Voltage, V _{OUT} UCN5821A & UCN5821LW 50 V UCN5822A & UCN5822LW 80 V
Logic Supply Voltage, V _{DD} 15 V
Input Voltage Range,
V_{IN} 0.3 V to V_{DD} + 0.3 V
Continuous Output Current,
I _{OUT} 500 mA
Package Power Dissipation, P _D
Package Code 'A'
Package Code 'LW' 1.5 W
Operating Temperature Range,
T _A 20°C to +85°C
Storage Temperature Range,
T _S 55°C to +150°C

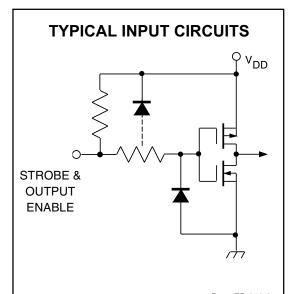
Caution: CMOS devices have input static protection but are susceptible to damage when exposed to extremely high static electrical charges.

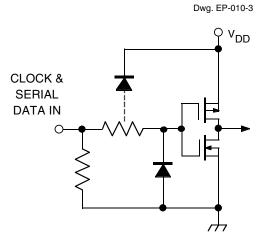
FEATURES

- To 3.3 MHz Data Input Rate
- CMOS, NMOS, TTL Compatible
- Internal Pull-Down Resistors
- Low-Power CMOS Logic & Latches
- High-Voltage Current-Sink Outputs
- Automotive Capable

Always order by complete part number, e.g., UCN5821A.

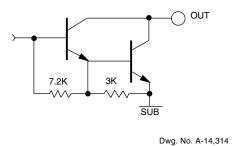




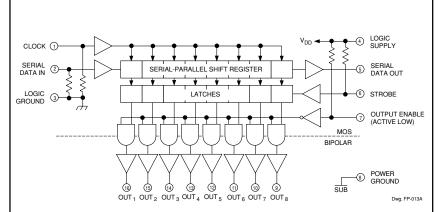


Dwg. EP-010-4A

TYPICAL OUTPUT DRIVER



FUNCTIONAL BLOCK DIAGRAM



NOTE — There is an indeterminate resistance between logic ground and power ground. For proper operation, these terminals must be externally connected together.

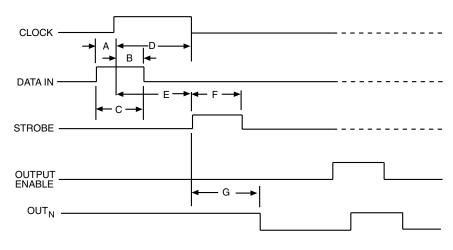
Number of Outputs ON (I _{OUT} = 200 mA	UCN5821A Max. Allowable Duty Cycle at Ambient Temperature of								
V _{DD} = 12 V)	25°C	40°C	50°C	60°C	70°C				
8	90%	79%	72%	65%	57%				
7	100%	90%	82%	74%	65%				
6	100%	100%	96%	86%	76%				
5	100%	100%	100%	100%	91%				
4	100%	100%	100%	100%	100%				
3	100%	100%	100%	100%	100%				
2	100%	100%	100%	100%	100%				
1	100%	100%	100%	100%	100%				

Number of Outputs ON (I _{OUT} = 200 mA	UCN5821LW Max. Allowable Duty Cycle at Ambient Temperature of							
V _{DD} = 12 V)	25°C	40°C	50°C	60°C	70°C			
8	67%	59%	54%	49%	43%			
7	77%	68%	62%	56%	49%			
6	90%	79%	72%	65%	57%			
5	100%	95%	86%	78%	68%			
4	100%	100%	100%	98%	86%			
3	100%	100%	100%	100%	100%			
2	100%	100%	100%	100%	100%			
1	100%	100%	100%	100%	100%			



ELECTRICAL CHARACTERISTICS at T_A = +25°C, V_{DD} = 5 V, (unless otherwise specified).

				Limits		
Characteristic	Symbol	Test Conditions	Min.	Max.	Units	
Output Leakage	I _{CEX}	UCN5821A/LW, V _{OUT} = 50 V	–	50	μΑ	
Current		UCN5822A/LW, V _{OUT} = 80 V	_	50	μА	
		UCN5821A/LW, V _{OUT} = 50 V, T _A = +70°C	_	100	μΑ	
		UCN5822A/LW, V _{OUT} = 80 V, T _A = +70°C	_	100	μΑ	
Collector-Emitter	V _{CE(SAT)}	I _{OUT} = 100 mA	_	1.1	V	
Saturation Voltage		I _{OUT} = 200 mA	_	1.3	V	
		$I_{OUT} = 350 \text{ mA}, V_{DD} = 7.0 \text{ V}$	_	1.6	V	
Input Voltage	V _{IN(0)}		_	0.8	V	
	V _{IN(1)}	V _{DD} = 12 V	10.5	_	V	
		V _{DD} = 5.0 V	3.5	_	V	
Input Resistance	r _{IN}	V _{DD} = 12 V	50	_	kΩ	
		V _{DD} = 5.0 V	50	_	kΩ	
Supply Current	I _{DD(ON)}	One Driver ON, V _{DD} = 12 V	_	4.5	mA	
		One Driver ON, V _{DD} = 10 V	_	3.9	mA	
		One Driver ON, V _{DD} = 5.0 V		2.4	mA	
	I _{DD(OFF)}	V _{DD} = 5.0 V, All Drivers OFF, All Inputs = 0 V	_	1.6	mA	
		V _{DD} = 12 V, All Drivers OFF, All Inputs = 0 V		2.9	mA	



Dwg. No. A-12,627

TIMING CONDITIONS $(V_{DD} = 5.0 \text{ V}, T_A = +25^{\circ}\text{C}, \text{Logic Levels are } V_{DD} \text{ and Ground})$

Α.	Minimum Data Active Time Before Clock Pulse	
	(Data Set-Up Time)75	ns
В.	Minimum Data Active Time After Clock Pulse	
	(Data Hold Time)75	ns
C.	Minimum Data Pulse Width	ns
D.	Minimum Clock Pulse Width150	ns
E.	Minimum Time Between Clock Activation and Strobe30	ns
F.	Minimum Strobe Pulse Width	ns
G.	Typical Time Between Strobe Activation and	
	Output Transition	μs

Serial Data present at the input is transferred to the shift register on the logic "0" to logic "1" transition of the CLOCK input pulse. On succeeding CLOCK pulses, the registers shift data information towards the SERIAL DATA OUTPUT. The SERIAL DATA must appear at the input prior to the rising edge of the CLOCK input waveform.

Information present at any register is transferred to its respective latch when the STROBE is high (serial-to-parallel conversion). The latches will continue to accept new data as long as the STROBE is held high. Applications where the latches are bypassed (STROBE tied high) will require that the ENABLE input be high during serial data entry.

When the ENABLE input is high, all of the output buffers are disabled (OFF) without affecting the information stored in the latches or shift register. With the ENABLE input low, the outputs are controlled by the state of the latches.

TRUTH TABLE

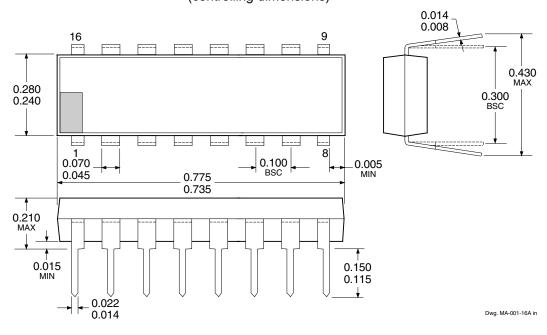
Serial			hift	Regi	ister Cont	ents	Serial	0	Latch Contents				Output Contents					
1	Clock Input		l ₂	I ₃		I ₈	Data Output	Strobe Input	l ₁	l ₂	l ₃	l ₈	Output Enable	I ₁	l ₂	l ₃		l ₈
Н	۲	Н	R ₁	R ₂		R ₇	R ₇											
L	卜	L	R ₁	R_2		R ₇	R ₇											
Х	니	R ₁	R ₂	R ₃		R ₈	R ₈											
		Х	Χ	Χ		Χ	Х	L	R ₁	R ₂	R ₃	R ₈						
		P ₁	P ₂	P ₃		P ₈	P ₈	Н	P ₁	P ₂	P ₃	P ₈	L	P ₁	P ₂	P ₃		P ₈
									Χ	X	X	X	Н	Н	Н	Н		Н

L = Low Logic Level H = High Logic Level X = Irrelevant P = Present State R = Previous State

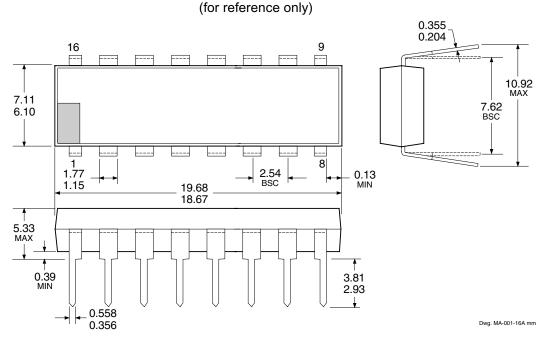


UCN5821A and UCN5822A Dimensions in Inches

(controlling dimensions)



Dimensions in Millimeters

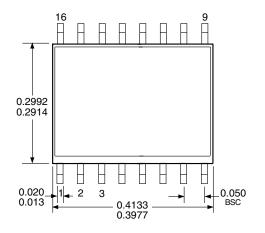


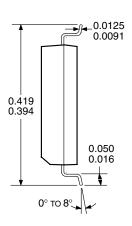
NOTES: 1. Lead thickness is measured at seating plane or below.

- 2. Lead spacing tolerance is non-cumulative.
- 3. Exact body and lead configuration at vendor's option within limits shown.

UCN5821LW and UCN5822LW

Dimensions in Inches (for reference only)

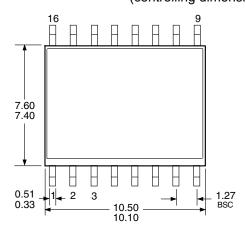


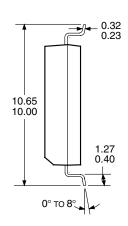


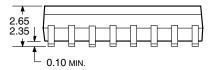


Dwg. MA-008-16A in

Dimensions in Millimeters (controlling dimensions)







Dwg. MA-008-16A mm

NOTES: 1. Lead spacing tolerance is non-cumulative.

2. Exact body and lead configuration at vendor's option within limits shown.



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POWER INTERFACE DRIVERS

Function	Output Ratings*								
SERIAL-INPUT LATCHED DRIVERS									
8-Bit (saturated drivers)	-120 mA	50 V‡	5895						
8-Bit	350 mA	50 V	5821						
8-Bit	350 mA	80 V	5822						
8-Bit	350 mA	50 V‡	5841						
8-Bit	350 mA	80 V‡	5842						
8-Bit (constant-current LED driver)	75 mA	17 V	6275						
8-Bit (DMOS drivers)	250 mA	50 V	6595						
8-Bit (DMOS drivers)	350 mA	50 V‡	6A595						
8-Bit (DMOS drivers)	100 mA	50 V	6B595						
10-Bit (active pull-downs)	-25 mA	60 V	5810-F and 6809/10						
12-Bit (active pull-downs)	-25 mA	60 V	5811 and 6811						
16-Bit (constant-current LED driver)	75 mA	17 V	6276						
20-Bit (active pull-downs)	-25 mA	60 V	5812-F and 6812						
32-Bit (active pull-downs)	-25 mA	60 V	5818-F and 6818						
32-Bit	100 mA	30 V	5833						
32-Bit (saturated drivers)	100 mA	40 V	5832						
PARALLEI	L-INPUT LATCHED	DRIVERS							
4-Bit	350 mA	50 V‡	5800						
8-Bit	-25 mA	60 V	5815						
8-Bit	350 mA	50 V‡	5801						
8-Bit (DMOS drivers)	100 mA	50 V	6B273						
8-Bit (DMOS drivers)	250 mA	50 V	6273						
SPEC	IAL-PURPOSE DEV	ICES							
Unipolar Stepper Motor Translator/Driver	1.25 A	50 V‡	5804						
Addressable 8-Bit Decoder/DMOS Driver	250 mA	50 V	6259						
Addressable 8-Bit Decoder/DMOS Driver	350 mA	50 V‡	6A259						
Addressable 8-Bit Decoder/DMOS Driver	100 mA	50 V	6B259						
Addressable 28-Line Decoder/Driver	450 mA	30 V	6817						

^{*} Current is maximum specified test condition, voltage is maximum rating. See specification for sustaining voltage limits. Negative current is defined as coming out of (sourcing) the output.



[†] Complete part number includes additional characters to indicate operating temperature range and package style.

[‡] Internal transient-suppression diodes included for inductive-load protection.